

Series 195 Octave-Band PIN Diode Attenuator/Modulator



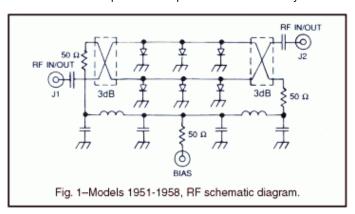
Application Notes for Microwave Attenuators

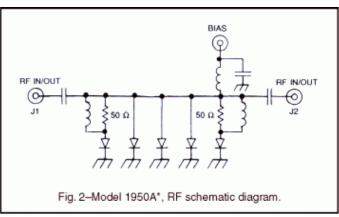
SERIES 195

Series 195 current-controlled attenuator/modulators provide small size with greater than octave-bandwidth performance at low cost. All models except the 1950A* provide a minimum of 60 dB of attenuation with fall times of 20 nsec max, and rise times ranging from 25 nsec for the 1951 and 1952 to 125 nsec max for the 1956 and 1958. The 1950A* provides a minimum of 80 dB of attenuation with a fall time of 50 nsec max and a rise time of 250 nsec max. These characteristics make this series suitable for a wide range of applications including level setting, complex amplitude modulation, pulse modulation and high-speed switching. The eight models in the Series 195 encompass a frequency range from 0.5 to 18 GHz. All models except the 1950A* are capable of extended bandwidth operation, typically 3:1, with only moderate degradation in performance at the band edges.

As shown in figures 1 and 2 below, the RF circuit employed in all models except the Model 1950A* uses two shunt arrays of PIN diodes and two quadrature hybrid couplers. The quadrature hybrids are of a unique GMC microstrip design which are integrated with the diode arrays to yield a minimal package size. The RF circuit employed in the Model 1950A* uses one shunt array of PIN diodes with input and output impedance matching circuits.

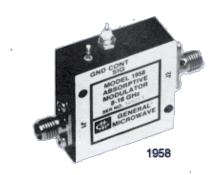
*Model 1950A is a special-order product. Consult factory before ordering.

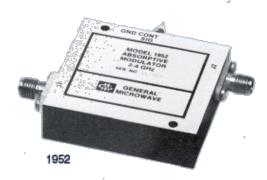


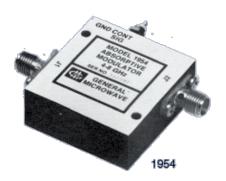




- Current controlled
- 0.5 to 18 GHz frequency range
- High performance MIC quadrature hybrid design
- High speed







				MAX. FLATNESS (± dB) AT MEAN ATTENUATION LEVELS UP TO				
MODEL	FREQUENCY RANGE (GHz)	MAX. INSERTION LOSS	MAX. VSWR	10 dB	20 dB	40 dB	60 dB	80 dB
1950A*	0.5 - 1.0	1.4	2.0	0.3	1.0	1.7	2.2	3.2
	1.0 - 2.0	1.3	1.5	0.3	1.0	1.5	1.6	

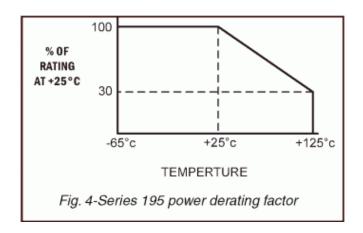
1951	0.75 - 2.25 ⁽¹⁾	1.4	2.0	0.5	1.4	3.0	3.5
4050	2.0 - 4.0	1.5	1.5	0.3	1.0	1.5	1.6
1952	1.5 - 4.5 ⁽¹⁾	1.6	2.0	0.5	1.4	3.0	3.5
4052	2.6 - 5.2	1.7	1.6	0.3	1.0	1.5	1.6
1953	1.95 - 5.85 ⁽¹⁾	1.8	2.1	0.5	1.4	3.0	3.5
1954	4.0 - 8.0	2.0	1.7	0.3	1.0	1.5	1.6
1904	3.0 - 9.0 ⁽¹⁾	2.1	2.2	0.5	1.4	3.0	3.5
1055	5.0 - 10.0	2.2	1.7	0.5	1.0	1.5	1.6
1955	3.75 - 11.25 ⁽¹⁾	2.3	2.2	0.7	1.4	3.0	3.5
1956	6.0 - 12.0	2.3	1.8	0.7	1.0	1.5	1.6
1900	4.5 - 13.5 ⁽¹⁾	2.4	2.2	0.9	1.5	3.0	3.5
1059	8.0 - 18.0	2.5 ⁽²⁾	1.8 ⁽²⁾	0.7	1.0	1.5	1.6
1958	6.0 - 18.0 ⁽¹⁾	2.5 ⁽²⁾	1.8 ⁽²⁾	0.9	1.5	3.0	3.5

⁽¹⁾ Specifications for the extended frequency ranges are typical.

PERFORMANCE CHARACTERISTICS

Mean Attenuation Range		Switching Speed		
1950A*	80 dB	Fall Time		
All other units	60 dB	195OA*	50 nsec max(3)	
Monotonicity	Guaranteed	All other units	20 nsec max(3)	
Phase Shift	See Application Note	Rise Time	· ,	
Temperature Effects	See Fig. 3			
Power Handling Capability	-	195OA*	. 250 nsec max(3)	
Without Performance Degrada	tion	All other units	125 nsec max(3)	
1950A*,1951	10 mW cw or peak	Bias Current for Maximum Attenua	tion	
All other units	100 mW cw or peak	195OA*	5 to 35 mA	
Survival Power (from -65°C see Fig. 4 for higher temper	*	All other units	15 to 70 mA	
All units	1 W average 25W peak (1 µsec max pulse width)	(3) For attenuation steps of 10 dB or	more.	

^{*}Model 1950A is a special-order product. Consult factory before ordering.



⁽²⁾ Except from 16-18 GHz where insertion loss is 3.5 dB max and VSWR is 2.0 max

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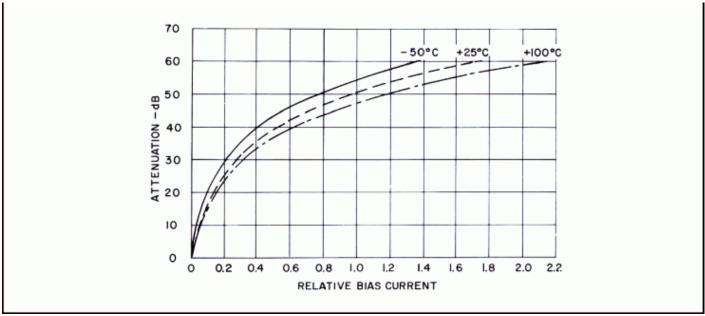


Fig 3—Series 195, typical effects of temperature on attenuation

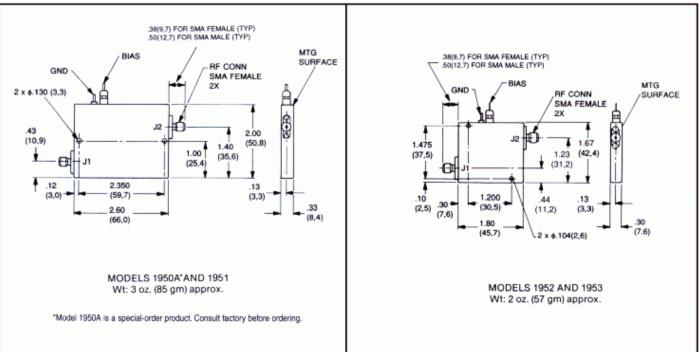
ENVIRONMENTAL RATINGS

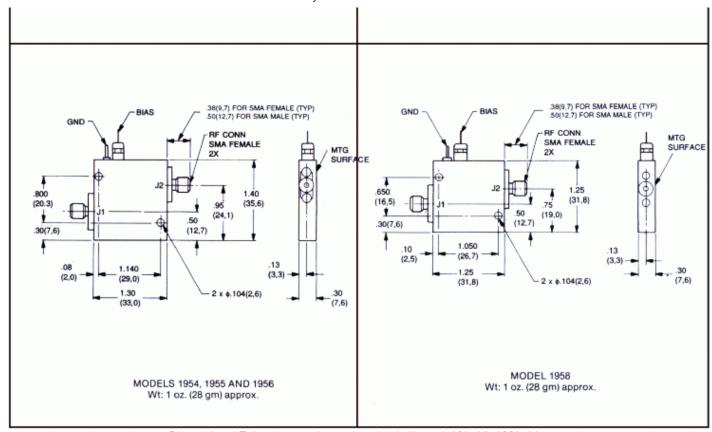
Range	-54°C to + 125°C
Non-Operating Temperature Range	-65°C to + 125°C
Humidity	MIL-STD-202F, Method 103B, Cond. B (96 hrs. at 95%)
Shock	MIL-STD-202F, Method 213B, Cond. B (75G, 6 msec)
Vibration	MIL-STD-202F, Method 204D, Cond. B (.06" double amplitude or 15G, whichever is less)
Altitude	MIL-STD-202F, Method 105C, Cond. B (50,000 ft.)
Temp. Cycling	MIL-STD-202F, Method 107D, Cond. A, 5 cycles

AVAILABLE OPTIONS

Option No.	Description
3	SMA female bias connector
7	Two SMA male rf connectors
10	One SMA male (J1) and one SMA female (J2) rf connector
64	SMC male bias connector
64A	SMB male bias connector

DIMENSIONS AND WEIGHTS





Dimensional Tolerances, unless otherwise indicated: .XX±.02; .XXX±.005



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